Central Semiconductor Corp.

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Manufacturers of World Class Discrete Semiconductors

2N5490 2N5492 2N5494 2N5496

NPN SILICON POWER TRANSISTORS

JEDEC TO-220AB CASE

DESCRIPTION

The CENTRAL SEMICONDUCTOR 2N5490 series types are Silicon NPN Power Transistors designed for medium power and amplifier applications.

MAXIMUM RATINGS (TC=25°C)

	SYMBOL	2N5490 2N5494	2N5492	2N5496	UNIT	
Collector-Base Voltage Collector-Emitter Voltage (V _{BE} =1.5V) Collector-Emitter Voltage (R _{BE} =100Ω) Collector-Emitter Voltage Emitter-Base Voltage Collector Current Base Current Power Dissipation Operating and Storage	VCBO VCEV VCER VCEO VEBO IC IB PD	60 60 50 40 5.0 7.0 3.0	75 75 65 55 5.0 7.0 3.0 50	90 90 80 70 5.0 7.0 3.0	V V V V A A	
Junction Temperature	Tj, T _{stq}		-65 TO +150			
Thermal Resistance	өлс	2.5	2.5	2.5	°C/W	

ELECTRICAL CHARACTERISTICS (T_C=25°C)

		2N5 ⁴	-	2N5 ^L	-	2N5 ¹		2N5 ⁴		114117
SYMBOL	TEST CONDITIONS	MIN	MAX	MIN	MAX	MIN	MAX	MIN	MAX	UNIT
¹ CEV	V _{CE} =85V, V _{BE} =1.5V		1.0		-	•	_		_	mA
ICEV	V _{CE} =55V, V _{BE} =1.5V		-		1.0		-		-	mΑ
CEV	V _{CE} =70V, V _{BE} =1.5V		-		-		1.0		-	mΑ
ICER	V_{CE} =Rated V_{CEO} , R_{BE} =100	Ω	0.5		0.5		0.5		2.0	mΑ
I EBO	VBE=5.0V		1.0		1.0		1.0		1.0	mΑ
BVCEV	V _{BE} =1.5V, I _C =100mA	90		60		75		60		٧
BVCEB	$I_{C}=100$ mA, $R_{BE}=100$ Ω	80		50		65		50		V
RACEO	I _C =100mA	70		40		55		40		٧
VCE(SAT)	I _C =35A, I _B =0.35A		1.0		-		-		-	V
VCE(SAT)	I _C =3.0A, I _B =0.3A		-		1.0		-		-	٧
V _{CE} (SAT)	$I_{C}=2.5A$, $I_{B}=0.25A$		-		-		1.0		_	V
VCE(SAT)	$I_{C}=2.0A$, $I_{B}=0.2A$				-		-		1.0	V
VBE(ON)	$V_{CE}=4.0V$, $I_{C}=.35A$		1.7		-		-		-	٧
VBE(ON) -	$V_{CE}=4.0V$, $I_{C}=3.0A$		-		1.5		_		_	٧
VBE(ON)	$V_{CE}=4.0V$, $I_{C}=2.5A$		-		-		1.3		-	V
VBE(ON)	$V_{CE}=4.0V$, $I_{C}=2.0A$		-		-		-		1.1	V
hFE	$V_{CE}=4.0V, I_{C}=3.5A$	20	100	-	-	-	_	-	-	
hFE	VCE=4.0V, IC=3.0A	-	-	20	100	-	100	-	-	
hFE	V _{CE} =4.0V, I _C =2.5A	-	-	_	-	20	100	20	100	
hFE	VCE=4.0V, 1C=2.0A	-	-	- 0	-	-	_	20	100	Mit
fŢ	VCE=4.0V, IC=0.5A	0.8		0.8		0.8		0.8	- 0	MHz
ton	V _{CC} =30V		5.0	·	5.0		5.0		5.0	μs
corr	ΛCC-20Λ		15		15		15		15	μs

OUTSTANDING SUPPORT AND SUPERIOR SERVICES



PRODUCT SUPPORT

Central's operations team provides the highest level of support to insure product is delivered on-time.

- Supply management (Customer portals)
- · Inventory bonding
- · Consolidated shipping options

- · Custom bar coding for shipments
- · Custom product packing

DESIGNER SUPPORT/SERVICES

Central's applications engineering team is ready to discuss your design challenges. Just ask.

- Free guick ship samples (2nd day air)
- Online technical data and parametric search
- SPICE models
- · Custom electrical curves
- · Environmental regulation compliance
- · Customer specific screening
- · Up-screening capabilities

- Special wafer diffusions
- PbSn plating options
- Package details
- Application notes
- · Application and design sample kits
- Custom product and package development

REQUESTING PRODUCT PLATING

- 1. If requesting Tin/Lead plated devices, add the suffix "TIN/LEAD" to the part number when ordering (example: 2N2222A TIN/LEAD).
- 2. If requesting Lead (Pb) Free plated devices, add the suffix "PBFREE" to the part number when ordering (example: 2N2222A PBFREE).

CONTACT US

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